





IFBF510-1

IFBF510, IFBF511 N-Channel JFET

Technical

Support

Features

- InterFET <u>N0026 Geometry</u>
- Low Noise: 3 nV/VHz Typical
- Low Ciss: 5.0pF Maximum
- Low Leakage: 10pA Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

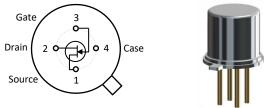
Applications

- Low Noise High Gain
- Replacement for BF510 and BF511
- Mixers
- Oscillators
- VHF Amplifiers

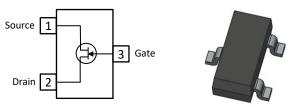
Description

The -20V InterFET IFBF510 and IFBF511 are targeted for low noise amplifier stages as well as mixer and oscillator designs. Gate leakages are typically less than 10pA at room temperatures. The TO-72 package is hermetically sealed and suitable for military applications.



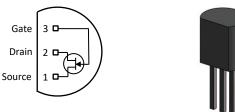






Note: The SOT23 package is pinned out differently than the BF51x part to optimize thermal performance. Package and pinout variations are available through InterFET custom ordering.

TO-92 Bottom View



Product Summary

	Parameters	IFBF510 Min	IFBF511 Min	Unit
BV _{GSS}	Gate to Source Breakdown Voltage	-20	-20	V
I _{DSS}	Drain to Source Saturation Current	0.7	2.5	mA
V _{GS(off)}	Gate to Source Cutoff Voltage	-0.8 (typ)	-1.5 (typ)	V
GFS	Forward Transconductance	2.5	4	mS

Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
IFBF510; IFBF511	Through-Hole	TO-72	Bulk
PNBF510; PNBF511	Through-Hole	TO-92	Bulk
SMPBF510; SMPBF511	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMPBF510TR; SMPBF511TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
IFBF510COT; IFBF511COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
IFBF510CFT; IFBF511CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.







Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
VRGS	Reverse Gate Source and Gate Drain Voltage	-20	V
I_{FG}	Continuous Forward Gate Current	10	mA
PD	Continuous Device Power Dissipation	300	mW
Р	Power Derating	1.7	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			IFBF510 IFBF511		511		
	Parameters	Conditions	Min	Max	Min	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	V _{DS} = 0V, I _G = -1µA	-20		-20		V
IGSS	Gate to Source Reverse Current	V _{GS} = -15V, V _{DS} = 0V, T _A = 25°C		-10		-10	nA
V _{GS(F)}	Gate to Source Forward Voltage	$V_{DS} = 0V, I_G = 1mA$		1		1	V
Vgs(off)	Gate to Source Cutoff Voltage	V _{DS} = 10V, I _D = 1nA	-0.5		-0.8		V
I _{DSS}	Drain to Source Saturation Current	$V_{GS} = 0V, V_{DS} = 10V$ (Pulsed)	0.7	3.0	2.5	7.0	mA

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			IFBF510		IFBF511		
	Parameters	Conditions	Min	Max	Min	Max	Unit
GFS	Forward Transconductance	V_{DS} = 10V, V_{GS} = 0V, f = 1kHz	2.5		4		mS
Gos	Output Conductance	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz		60		80	uS
Ciss	Input Capacitance	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz		5		5	pF
C _{rss}	Reverse Transfer Capacitance	V_{DS} = 10V, V_{GS} = 0V, f = 1MHz		1.5		1.5	pF



Technical

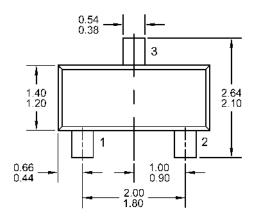
Support

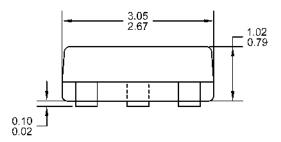
Order

Now

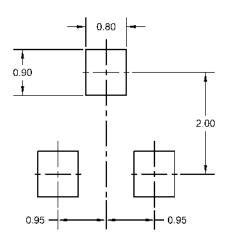
SOT23 (TO-236AB) Mechanical and Layout Data

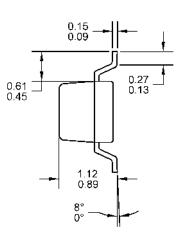
Package Outline Data





Suggested Pad Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



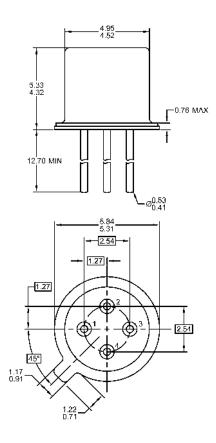


Order

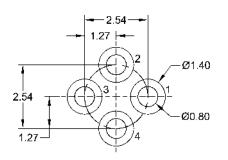
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TO-72 Mechanical and Layout Data

Package Outline Data



Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- 2. Four leaded device. Not all leads are shown in drawing views.
- 3. Package weight approximately 0.31 grams
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

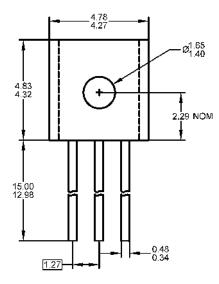
- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

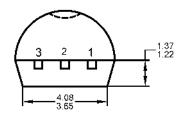




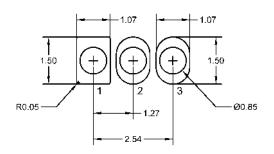
TO-92 Mechanical and Layout Data

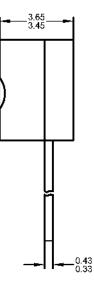
Package Outline Data





Suggested Through-Hole Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.